Amendments to the Claims

This listing of claims will replace all prior versions, and listings of claims in the application:

Listing of Claims:

Claim 1 (Canceled)

Claim 2 (Currently Amended): A ferroelectric capacitor comprising:

a <u>stepped</u> bottom electrode[[;]] <u>having a planar base electrode with</u> a plurality of projection electrodes fermed on the <u>bettom planar base</u> electrode;

a ferroelectric layer fermed on the <u>stepped</u> bottom electrode and the projection electrodes; and

a top planar electrode formed on the ferroelectric layer,

wherein a thickness of the ferroelectric layer on the projection electrodes is less than a thickness of the ferroelectric layer on the bettern planar base electrode, and wherein spacing between central portions of each projection electrode has a range from 10% to 20% of a size of the ferroelectric capacitor.

Claim 3 (Currently Amended): A ferroelectric capacitor comprising:

a <u>stepped</u> bottom electrode[[;]] <u>having a planar base electrode with</u> a plurality of projection electrodes formed on the bottom planar base electrode;

a ferroelectric layer formed on the <u>stepped</u> bottom electrode and the projection electrodes; and

a top planar electrode formed on the ferroelectric layer,

wherein a thickness of the ferroelectric layer on the projection electrodes is less than a thickness of the ferroelectric layer on the bettem planar base electrode, and wherein a size of each projection electrode has a range from 5% to 10% of a size of the ferroelectric capacitor.

Claim 4 (Withdrawn-Currently Amended): The ferroelectric capacitor of claim 2, wherein the top <u>planar</u> electrode includes <u>comprises</u> a plurality of second projection electrodes <u>thereon</u>, each of the plurality of second projection electrodes facing respective ones of the plurality of projection electrodes.

Claim 5 (Withdrawn-Currently Amended): The ferroelectric capacitor of claim 2, wherein the projection electrodes are made of bismuth or bismuth alloy.

Claim 6 (Withdrawn-Currently Amended): The ferroelectric capacitor of claim 5, wherein the bettem planar base electrode is made of a metal which includes bismuth.

Claim 7 (Currently Amended): A ferroelectric capacitor comprising:

a stepped bottom electrode[[;]] having a planar base electrode with a plurality of

projection electrodes formed on the bottom planar base electrode;

a ferroelectric layer formed on the <u>stepped</u> bottom electrode and the projection electrodes; and

a top planar electrode formed on the ferroelectric layer,

wherein the projection electrodes are arranged spaced apart from each other evenly, and

wherein a thickness of the ferroelectric layer on the projection electrodes is less than a thickness of the ferroelectric layer on the bettem planar base electrode, so that and cores of polarization inversion within the ferroelectric layer extend from the projection electrodes.

Claim 8 (Currently Amended): The ferroelectric capacitor of claim 2, wherein the bottom planar base electrode and the projection electrodes are made of a same material.

Claims 9 - 14 (Canceled)

Claim 15 (Currently Amended): A ferroelectric capacitor comprising:

a first <u>stepped</u> electrode[[;]] <u>comprising</u> a <u>second first planar</u> electrode[[;]] <u>having</u> a plurality of [[third]] <u>projection</u> electrodes on the first <u>planar</u> electrode and spaced apart from each other evenly;

a second planar electrode; and

a ferroelectric layer sandwiched between the first <u>stepped</u> electrode and the second planar electrode, and on the third-electrodes[I.I]

wherein a thickness of the ferroelectric layer on the [Ithird]] <u>projection</u> electrodes is less than a thickness of the ferroelectric layer on the second <u>planar</u> electrode, se-that <u>and</u> cores of polarization inversion within the ferroelectric layer extend from the [[third]] projection electrodes.

Claims 16-17 (Canceled)

Claim 18 (Currently Amended): The ferroelectric capacitor of claim 15, wherein the first planar electrode and the [[third]] projection electrodes are made by a same material.

Claim 19 (Withdrawn-Currently Amended): The ferroelectric capacitor of claim 15, further comprising additional electrodes on the second planar electrode electrodes.

Claim 20 (Withdrawn-Currently Amended): The ferroelectric capacitor of claim 3, wherein the top <u>planar</u> electrode includes <u>comprises</u> a plurality of second projection electrodes <u>thereon</u>, each of the plurality of second projection electrodes facing respective ones of the plurality of projection electrodes.

Claim 21 (Withdrawn-Currently Amended): The ferroelectric capacitor of claim 3, wherein the projection electrodes are made-of bismuth or bismuth alloy.

Claim 22 (Withdrawn-Currently Amended): The ferroelectric capacitor of claim 21, wherein the bettem <u>planar base</u> electrode is made of a metal which includes bismuth.

Claim 23 (Withdrawn-Currently Amended): The ferroelectric capacitor of claim 3, wherein the bettern planar base electrode and the projection electrodes are made of a same material.

Claim 24 (Withdrawn-Currently Amended): The ferroelectric capacitor of claim 7, wherein the top <u>planar</u> electrode includes <u>comprises</u> a plurality of second projection electrodes <u>thereon</u>, each of the plurality of second projection electrodes facing respective ones of the plurality of projection electrodes.

Claim 25 (Withdrawn-Currently Amended): The ferroelectric capacitor of claim 7, wherein the projection electrodes are made of bismuth or bismuth alloy.

Claim 26 (Withdrawn-Currently Amended): The ferroelectric capacitor of claim 25, wherein the bettem planar base electrode is made of a metal which includes bismuth.

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Claim 27 (Withdrawn-Currently Amended): The ferroelectric capacitor of claim 7, wherein the bettem <u>planar base</u> electrode and the projection electrodes are made of a same material.